

Description

The HXY2101EI uses advanced trench technology

to provide excellent $R_{DS(ON)}$, This device is suitable

for use as a load switch or in PWM applications.

General Features

 $V_{DS} = -20V, I_{D} = -1.8A$

 $R_{DS(ON)}$ < 150m Ω @ V_{GS} =-4.5V

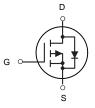
Application

Battery protection

Load switch

Uninterruptible power supply





P-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
HXY2101EI	SOT-323	TS1	3000

Absolute Maximum Ratings (TA=25 ℃ unless otherwise noted)

Symbol	Parameter	Limit	Unit
V _{DS}	Drain-Source Voltage	-20	V
V _G s	Gate-Source Voltage	±8	V
I _D	Drain Current-Continuous	-1.8	А
Ідм	Drain Current-Pulsed (Note 1)	-3	А
P _D	Maximum Power Dissipation	0.29	W
T _J ,T _{STG}	Operating Junction and Storage Temperature Range	-55 To 150	$^{\circ}$
Reja	Thermal Resistance, Junction-to-Ambient (Note 2)	431	°C/W



Electrical Characteristics (T_A=25°C unless otherwise noted)

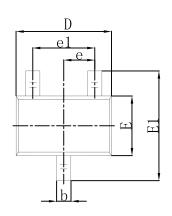
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
STATIC CHARACTERISTICE							
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =-250μA	-20			V	
Zero gate voltage drain current	I _{DSS}	V _{DS} =-18V,V _{GS} = 0V			-1	μA	
Gate-body leakage current	Igss	V _{GS} =±12V, V _{DS} = 0V			±100	nA	
Gate threshold voltage (note2)	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250µA	-0.4	-0.7	-1.0	V	
	R _{DS(on)}	V _{GS} =-4.5V, I _D =-2A			150	mΩ	
Drain-source on-resistance (note2)		V _{GS} =-2.5V, I _D =-1.0A			230	mΩ	
Maximum Continuous Drain to Source Diode Forward Current	Is				-1.0	А	
Diode forward voltage	V _{SD}	I _S =-1.0A, V _{GS} =0V			-1.2	V	
DYNAMIC CHARACTERISTICS (note3)							
Input capacitance	C _{iss}				680	pF	
Output capacitance	Coss	$V_{DS} = -8V, V_{GS} = 0V,$ $f = 1MHz$			130	pF	
Reverse transfer capacitance	C _{rss}	1 - 1101112			95	pF	
SWITCHING CHARACTERISTICS (note3)							
Turn-on delay time	t _{d(on)}				10	nS	
Turn-on rise time	t _r	V _{GS} =-4.5V,V _{DS} =-10V,			20	nS	
Turn-off delay time	t _{d(off)}	I _D =-1.0A,R _G =5.1Ω			35	nS	
Turn-off fall time	t _f				18	nS	

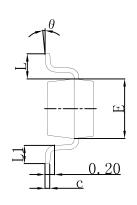
Notes:

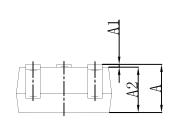
- 1. Surface mounted on FR4 board using the minimum recommended pad size.
- 2. Pulse Test: Pulse Width=300µs, Duty Cycle=2%.
- 3. These parameters have no way to verify.



SOT-323 Package Outline Dimensions







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.200	0.400	0.008	0.016	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.650	TYP	0.026 TYP		
e1	1.200	1.400	0.047	0.055	
L	0.525 REF		0.021 REF		
L1	0.260	0.460	0.010	0.018	
K	0°	8°	0°	8°	



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